## NSN 5961-00-229-1946

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View Online at https://aerobasegroup.com/nsn/5961-00-229-1946 **Inclosure Material:** Metal **Overall Length:** Between 0.280 inches and 0.320 inches **Terminal Length:** Between 0.480 inches and 0.520 inches **Overall Height:** Between 0.095 inches and 0.105 inches **Overall Width:** Between 0.360 inches and 0.405 inches **Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Anode **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 breakover voltage, dc **Current Rating Per Characteristic:** 2.40 amperes source cutoff current of standard range **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector preset **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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